BFR30LT1, BFR31LT1

JFET Amplifiers

N–Channel

Features

• Pb–Free Package is Available



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MAXIMUM RATINGS

Rating	Rating Symbol		Unit	
Drain-Source Voltage	V _{DS}	25	Vdc	
Gate-Source Voltage	V _{GS}	25	Vdc	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation (Note 1) $T_A = 25^{\circ}C$ Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^{\circ}C$ Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta J A}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

1. Device mounted on FR4 glass epoxy printed circuit board using the recommended footprint.

2. Alumina = $0.4 \times 0.3 \times 0.024$ in 99.5% alumina.



MARKING

ORDERING INFORMATION

Device	Package	Shipping [†]
BFR30LT1	SOT-23	3000/Tape & Reel
BFR30LT1G	SOT-23 (Pb-Free)	3000/Tape & Reel
BFR31LT1	SOT-23	3000/Tape & Reel
BFR31LT1G	SOT-23 (Pb-Free)	3000/Tape & Reel

⁺For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

	Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS						
Gate Reverse Current	$(V_{GS} = 10 \text{ Vdc}, V_{DS} = 0)$		I _{GSS}	-	0.2	nAdc
Gate Source Cutoff Voltage	$(I_D = 0.5 \text{ nAdc}, V_{DS} = 10 \text{ Vdc})$	BFR30 BFR31	V _{GS(OFF)}	-	5.0 2.5	Vdc
Gate Source Voltage	$(I_D = 1.0 \text{ mAdc}, V_{DS} = 10 \text{ Vdc})$ $(I_D = 50 \mu \text{Adc}, V_{DS} = 10 \text{ Vdc})$	BFR30 BFR31 BFR30 BFR31	V _{GS}	-0.7 - - -	-3.0 -1.3 -4.0 -2.0	Vdc
ON CHARACTERISTICS						
Zero-Gate-Voltage Drain Cu	rrent $(V_{DS} = 10 \text{ Vdc}, V_{GS} = 0)$	BFR30 BFR31	I _{DSS}	4.0 1.0	10 5.0	mAdc
SMALL-SIGNAL CHARACTE	RISTICS					
Forward Transconductance ($I_D = 1.0 \text{ mAdc}$, $V_{DS} = 10 \text{ Vol}$ ($I_D = 200 \mu \text{Adc}$, $V_{DS} = 10 \text{ Vol}$	dc, f = 1.0 kHz) dc, f = 1.0 kHz)	BFR30 BFR31 BFR30 BFR31	Yfs	1.0 1.5 0.5 0.75	4.0 4.5 -	mmhos
Output Admittance ($I_D = 1.0 \text{ mAdc}$, $V_{DS} = 10 \text{ Vol}$ ($I_D = 200 \mu \text{Adc}$, $V_{DS} = 10 \text{ Vol}$	dc, f = 1.0 kHz) dc)	BFR30 BFR31	Y _{os}	40 20	25 15	μmhos
Input Capacitance	$(I_D = 1.0 \text{ mAdc}, V_{DS} = 10)$ $(I_D = 200 \mu \text{Adc}, V_{DS} = 10)$	Vdc, f = 1.0 MHz) Vdc, f = 1.0 MHz)	C _{iss}	-	5.0 4.0	pF
Reverse Transfer Capacitance	e $(I_D = 1.0 \text{ mAdc}, V_{DS} = 10)$ $(I_D = 200 \mu \text{Adc}, V_{DS} = 10)$	Vdc, f = 1.0 MHz) Vdc, f = 1.0 MHz)	C _{rss}	-	1.5 1.5	pF



TYPICAL CHARACTERISTICS

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Note: Graphical data is presented for dc conditions. Tabular data is given for pulsed conditions (Pulse Width = 630 ms, Duty Cycle = 10%). Under dc conditions, self heating in higher I_{DSS} units reduces I_{DSS}.





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